arXiv:0907.3562v1 [cond-mat.mtrl-sci] 21 Jul 2009

# Anomalous transport properties of the halfmetallic ferromagnets $Co_2TiSi$, $Co_2TiGe$, and $Co_2TiSn$

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(Dated: July 21, 2009)

In this work the theoretical and experimental investigations of $Co_2TiZ$ ($Z$ = Si, Ge, or Sn) compounds are reported. Half-metallic ferromagnetism is predicted for all three compounds with only two bands crossing the Fermi energy in the majority channel. The magnetic moments fulfill the Slater-Pauling rule and the Curie temperatures are well above room temperature. All compounds show a metallic like resistivity for low temperatures up to their Curie temperature, above the resistivity changes to semiconducting like behavior. A large negative magnetoresistance of 55 % is observed for $Co_2TiSn$ at room temperature in an applied magnetic field of $\mu_0 H = 4\ T$ which is comparable to the large negative magnetoresistances of the manganites. The Seebeck coefficients are negative for all three compounds and reach their maximum values at their respective Curie temperatures and stay almost constant up to 950 K. The highest value achieved is -52 $\mu VK^{-1}m^{-1}$ for $Co_2TiSn$ which is large for a metal. The combination of half-metallicity and the constant large Seebeck coefficient over a wide temperature range makes these compounds interesting materials for thermoelectric applications and further spincaloric investigations.

PACS numbers: 72.15.Jf, 74.25.Ha, 74.25.Jb
Keywords: halfmetallic ferromagnets, electronic structure, Heusler compounds, thermoelectric properties

In the last few years Heusler alloys have attracted a lot of interest as suitable materials for spintronic applications [1]. A huge amount of theoretical and experimental studies investigating the half-metallic properties and enhancing the performance of the compounds and devices for different types of applications were done. In 2005, Hashemifar *et al* [2] showed in a density functional theory study the possibility to preserve the half-metallicity at the surface of the Heusler compound $Co_2MnSi(001)$. Very recently, Shan *et al* [3] demonstrated experimentally the half-metallicity of $Co_2FeAl_{0.5}Si_{0.5}$ at room temperature. The ability of growing well ordered half-metallic Heusler thin films on semiconductors (e.g. Ge (111)) makes Heusler compounds suitable for spininjection as shown by Hamaya *et al* [4]. The transport properties of pure and doped $Fe_2VAl$ show semiconductor like behavior with interesting and anomalous features near the structural transition temperature with an increasing absolute Seebeck coefficient with increasing temperature [5, 6]. The recent observation of the spin Seebeck effect allows to pass a pure spin current over a long distance [7] and is directly applicable to the production of spin-voltage generators which are crucial for driving spintronic devices [8, 9, 10]. To generate effectively a spin current and for other spincaloric applications as well one needs half-metals with a constant Seebeck effect behavior [11]. A constant Seebeck effect in dependence of the temperature is found especially in correlated systems such as pure and doped $SrRuO_3$ [12]. It can also be achieved e.g. in PbTe crystals with a sophisticated and experimentally complex graded Indium doping through the crystal [13]. This report will show that the Heusler compounds $Co_2TiSi$, $Co_2TiGe$, and $Co_2TiSn$ combine all requirements for the demand of half-metallic ferromagnets with a constant behavior of the Seebeck coefficient to be used in future for spincaloric devices. A big advantage is the easy tunability of the properties of the Heusler compounds which makes it easy to design new materials [14, 15].

The electronic structure of the compounds was calculated by means of the full potential linearized augmented plane wave (FLAPW) method [16, 17]. Details of the calculations are reported in Ref. [18]. The calculated band structure of $Co_2TiGe$ is shown in Figure 1. A band gap in the minority states occurs at the Fermi energy $\epsilon_F$. This minority gap is characteristic for half-metallic materials as was previously shown by various authors [18, 19, 20, 21, 22]. The size of the minority band gap amounts to $\Delta E_{\mathrm{HMF}} = 500$ meV and the Fermi energy is located close to the minimun of the conduction band. This was just confirmed by the experimental investigation of the spin-resolved unoccupied density of states [23]. The majority band structure is metallic with only two bands crossing $\epsilon_F$ and an electronic instability (van-Hove singularity) close to the $L$ point just below $\epsilon_F$. Due to the band gap in the minority states the magnetic moment is integer and has a value of exactly 2 $\mu_B$ for the primitive cell. A closer analysis shows that the magnetic moment is located at the Co atoms only. That means,

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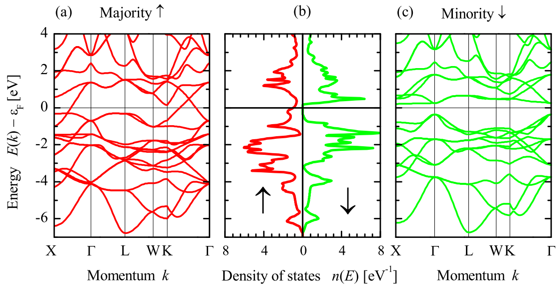

FIG. 1: Spin resolved electronic structure of $Co_2TiGe$. Shown are the band structures for the majority (a) and minority (c) electrons together with the density of states (b).

each of the two Co atoms in the primitive cell carries a magnetic moment of 1 $\mu_B$.

The $Co_2TiZ$ samples were produced by arc melting of stoichiometric amounts of the elements and afterwards annealed in evacuated quartz tubes for 21 days. For more details about the sample preparation see Ref. [24]. All samples exhibit the $L2_1$ structure and the lattice parameters at 300 K are determined to $a = 5.733$ Å, $a = 5.819$ Å, and $a = 6.066$ Å for $Co_2TiSi$, $Co_2TiGe$, and $Co_2TiSn$, respectively. The obtained values are in good agreement with previously published values [25, 26, 27].

The magnetic properties of the $Co_2TiZ$ samples were investigated by a super conducting quantum interference device (SQUID, Quantum Design MPMS-XL-5). The $Co_2$-based Heusler alloys that are half-metallic ferromagnets show a Slater-Pauling like behavior for the magnetization, what means that the saturation magnetization scales linearly with the number of valence electrons [21, 28]. This results in a theoretical magnetic moment of 2 $\mu_B$ per formula unit at T=0 K for all three compounds.

The saturation magnetization data measured at 5 K are shown in Figure 2 and reveal that all three compounds fulfil the Slater-Pauling rule and therefore are potential half-metallic ferromagnets. The magnetic moments at 5 K are 1.96 $\mu_B$, 1.94 $\mu_B$, and 1.97 $\mu_B$ per formula unit for $Co_2TiSi$, $Co_2TiGe$, and $Co_2TiSn$, respectively. The Curie temperature $T_C$ was determined from the temperature dependence of the magnetisation measured in an induction field of $\mu_0 H = 10 mT$ (see inset of Figure 2). The values for $T_C$ are 380 K for $Co_2TiSi$ and $Co_2TiGe$, and 355 K for $Co_2TiSn$ .

The measurements of the transport and thermoelectric properties were carried out with a Physical Property Measurement System (Model 6000 Quantum Design) on bars of about $(2 \times 2 \times 8)$ mm$^3$ which were cut from the pellets and polished before the measurement. The resistivity data for temperatures from 2 K to 400 K were obtained by a standard AC four probe method and the data from 350 K to 950 K were measured by a standard DC four point method.

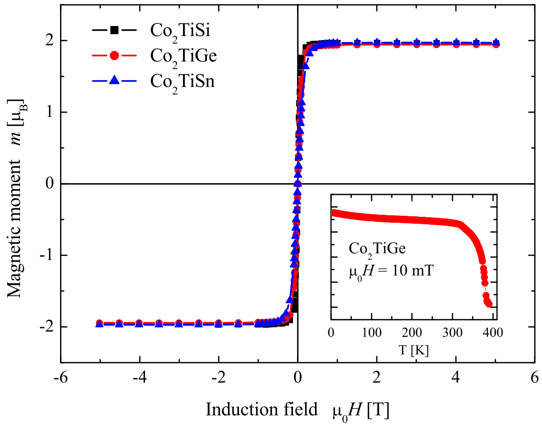

FIG. 2: Magnetization measurements of $Co_2TiZ$. Displayed are the hysteresis curves at 5K for $Co_2TiSi$, $Co_2TiGe$, and $Co_2TiSn$. The inset shows the temperature dependence measured in an induction field of $\mu_0 H = 10 mT$ for $Co_2TiGe$.

Figure 3(a) shows the temperature dependence of the resistivity $\rho$ for $Co_2TiSi$, $Co_2TiGe$, and $Co_2TiSn$. The resistivity behavior is metallic for all compounds in the low temperature range from 2 K to the respective Curie temperature. At $T_C$ a cusp-type transition is observed [29]. From there the resistivity declines to 550 K and stays nearly constant at higher temperatures. The Curie temperatures can be estimated from the maxima of the resistivities. The determined values are 370 K, 350 K, and 360 K for $Co_2TiSi$, $Co_2TiGe$, and $Co_2TiSn$, respectively. The values agree well with the ones obtained from the magnetic measurements. The measurements agree well with previous findings of other investigations for temperatures below 450 K [30]. Above $T_C$, a decrease of the resistivity is observed. The decrease is very pronounced up to about 600 K and stays nearly constant at higher temperatures. This behavior leads to a significant anomaly of the resistivity at $T_C$. Other than in many ferromagnetic materials, here the Curie temperature can be easily related to the maximum of the resistivity.

Similar, cusp-type anomalies of the resistivity close to $T_C$ are very typical for the manganites which show a large negative magnetoresistance (MR) around $T_C$ [31, 32]. This was observed in $GdI_2$ as well which shows a large room temperature MR of around 70 % at 7 T [33]. For intermetallic compounds these anomalies were only observed for Heusler compounds [34, 35]. In Figure 3(b) the magnetoresistance of $Co_2TiSn$ at $T$=306 K is shown as defined by $[R(B) - R(0\ Oe)]/R(0\ Oe)$. In an applied magnetic field of $\mu_0 H = 4\ T$ the MR exceeds 55 % which is an enormous value for a polycrystalline sample at room temperature.

Figure 4 shows the Seebeck coefficient (S) that was measured for temperatures from 2 K to 950 K. The values decrease with increasing temperature up to the Curie

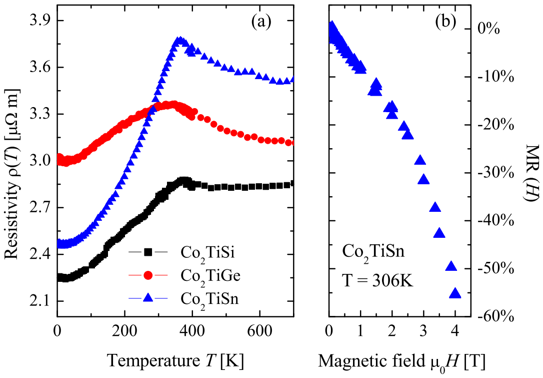

FIG. 3: Measured temperature dependent electrical resistivity $\rho$ of $Co_2TiZ$ compounds with Z = Si, Ge, or Sn (a). Magnetoresistance as a function of the applied magnetic field for $Co_2TiSn$ at $T$=306 K (b).

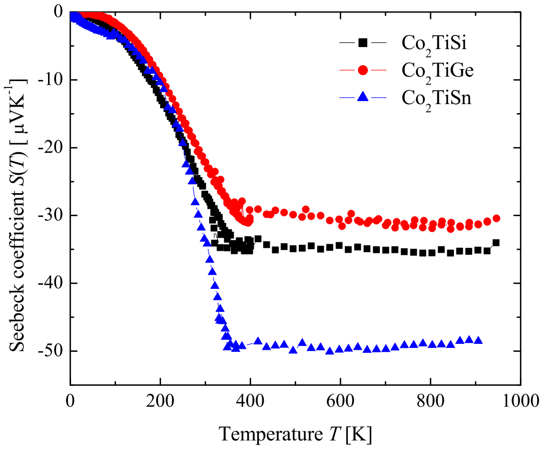

FIG. 4: Measured Seebeck coefficient of $Co_2TiZ$ compounds with Z = Si, Ge, or Sn.

temperature and stay almost constant at higher temperature. The mean values above $T_C$ are -35 $\mu VK^{-1}$, -31 $\mu VK^{-1}$, or -51 $\mu VK^{-1}$ for $Co_2TiSi$, $Co_2TiGe$, and $Co_2TiSn$, respectively. The maximum absolute values are rather large compared to the most elemental metals and are close to the Seebeck coefficient of elemental Co that exhibits about -30 $\mu VK^{-1}$ to -45 $\mu VK^{-1}$ at temperatures between 300 K and 500 K.

The Seebeck coefficient of all three investigated compounds is negative over the entire temperature range. For $Co_2TiSn$ a negative increase of the Seebeck coefficient is observed at about 80 K. This is close to $T/\Theta_D \approx 0.2$ with $\Theta_D$ being the Debye temperature where the largest influence of a phonon drag is expected. This assumption is in agreement with the measurement of the thermal conductivity where a peak at low temperatures is observed. The Seebeck coefficient provides a sensitive test of the electronic structure for metals in the vicinity of the Fermi energy. The rather large constant Seebeck coefficients above the Curie temperatures up to at least 950 K could be achieved by filling up the flat band in the $\Delta$ direction in the minority spin channel just above $\epsilon_F$ (see Figure 1(c)). The constant Seebeck coefficients above the Curie temperatures mean that the energy of the Fermi level is pinned in a wide temperature range in these compounds [13, 36] and therefore the thermovoltages have a linear temperature dependence which makes these compounds suitable materials for future thermoelectric devices such as thermocouples. With an Al-doping of the $Z$-Position in the $Co_2TiZ$ ($Z$ = Si, Ge, or Sn) compounds one can tune their Curie temperature to lower values [37] and therefore tune the working temperature of thermocouples designed out of these materials. In cubic systems the Seebeck coefficient is derived from the scalar electrical resistivity $\rho$ and thermal conductivity $\nu$: $S = \rho \times \nu$. Therefore, the constant value of the Seebeck effect means that the product of $\rho$ and $\nu$ have to be constant so they have to compensate each others dependency.

In summary, the $Co_2TiZ$ (Z = Si, Ge, or Sn) compounds were investigated theoretically and experimentally. Band structure calculations predict half-metallic ferromagnetism for all three compounds. The size of the minority band gap amounts to $\Delta E_{\mathrm{HMF}} = 500$ meV and the Fermi energy is located close to the middle of the gap. The majority band structure is metallic with a single band crossing $\epsilon_F$ in the $\Delta$ direction. The Curie temperature and the magnetic moment were determined by SQUID measurements and reveal that all three compounds fulfill the requirement for half-metallicity according to the Slater-Pauling rule and have Curie temperatures well above room temperature. All compounds show a metallic like resistivity for low temperatures up to their Curie temperature. From there on they change to semiconducting like behavior. This behavior is attributed to a ferromagnetic to paramagnetic transition, that strongly influences the band structure. The Seebeck coefficients are all negative and reach their maximum values at their respective Curie temperatures. The highest value achieved is -52 $\mu VK^{-1}m^{-1}$ for $Co_2TiSn$. Furthermore, the Seebeck coefficients of all three compounds are rather large for metals and constant above the Curie temperatures. Therefore the temperature dependence of the thermovoltages is linear which ensures a stable conversion efficiency even at high temperatures. This makes the compounds very attractive as materials for thermocouples or thermoelectric generators. The combination of half-metallicity and the constant large Seebeck coefficient over a wide temperature range makes these compounds interesting materials for further spincaloric and thermoelectric investigations. This work is financially supported by "Stiftung Innovation Rheinland-Pfalz", the Deutsche Forschungsgemeinschaft DFG (projects P 01 and P 07 in research unit FG 559) and DAAD (D06/33952).

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